

# KRCLAMP0521P-N

**Ultra Low Capacitance ESD Protection Diode** 

#### **DESCRIPTION**

KRCLAMP0521P-N a low-capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for With high-speed data interfaces. typical capacitance of 0.5pFKRCLAMP0521P-Ndesigned to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4 (±15kV air, ±8kV contact discharge), IEC 61000-4-4 (electrical fast transient - EFT) (40A, 5/50 ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

KRCLAMP0521P-Nultra-small 0402 package. EachKRCLAMP0521P-Ndevice can protect one high-speed data line. It offers system designers flexibility to protect single data line where space is a premium concern. The combined features of low capacitance, ultra-small size and high ESD robustness make KRCLAMP0521P-Nideal for high-speed data port and high-frequency line applications, such as cellular phones and HD visual devices.

### **FEATURES**

IEC 61000-4-4 (EFT) 40A (5/50 ns) Cable Discharge Event (CDE)

- ♦ Package optimized for high-speed lines
- ♦Ultra-small package (1.0mm×0.6mm×0.5mm)
- ♦Protects one data, control line
- ♦Low capacitance: 0.5pF (Typical)
- ♦Low leakage current
- ♦Low clamping voltage

#### **MACHANICAL DATA**

- ♦ Flammability Rating: UL 94V-0
- ♦ Packaging: Tape and Reel
- ♦High temperature soldering guaranteed: 260°C/10s
- ♦Reel size: 7 inch

#### ORDERING INFORMATION

→ Package: 0402→ Marking: N

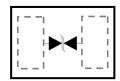
♦ Material: Halogen free♦ Packing: Tape & Reel

♦ Quantity per reel: 10,000pcs

#### **APPLICATIONS**

- ♦ Serial ATA
- ♦ Desktops, Servers and Notebooks
- ♦ Cellular Phones
- ♦MDDI Ports
- ♦USB Data Line Protection
- ♦ Display Ports
- ♦ Digital Visual Interfaces (DVI)

#### **PIN CONFIGURATION**



#### **PACKAGE OUTLINE**





KRCLAMP0521P-N
Ultra Low Capacitance ESD Protection Diode

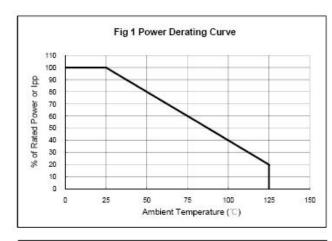
ABSOLUTE I	ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units					
$V_{ESD}$	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±20 ±20	kV					
P <sub>PP</sub>	Peak Pulse Power (8/20µs)	100	W					
T <sub>OPT</sub>	Operating Temperature	-55~125	°C					
T <sub>STG</sub>	Storage Temperature	-55~150	°C					

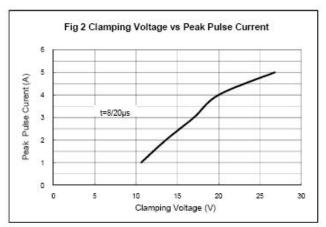
ELECTRICAL CHARACTERISTICS (Tamb=25°C)								
Symbol	Parameter	Test Condition	Min	Тур	Max	Units		
$V_{RWM}$	Reverse Working Voltage				5.0	V		
$V_{BR}$	Reverse Breakdown Voltage	I <sub>T</sub> = 1mA	6.0			V		
I <sub>R</sub>	Reverse Leakage Current	V <sub>RWM</sub> = 5V			100	nA		
V <sub>C</sub>	Clamping Voltage	$I_{PP} = 1A, t_p = 8/20 \mu s$			13	V		
		$I_{PP} = 4A, t_p = 8/20 \mu s$			25	V		
CJ	Junction Capacitance	V <sub>R</sub> = 0V, f = 1MHz		0.5		pF		

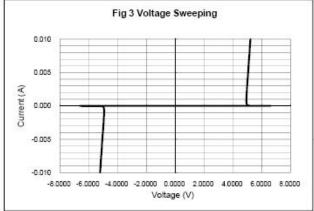


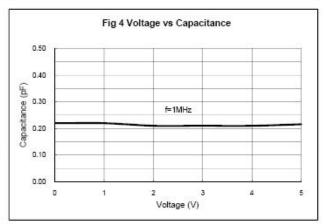


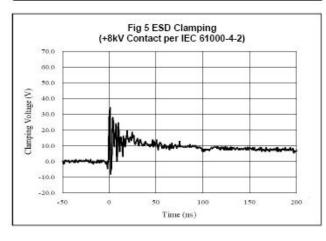
# **ELECTRICAL CHARACTERISTICS CURVE**

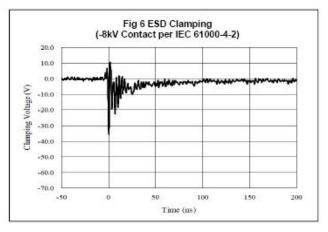








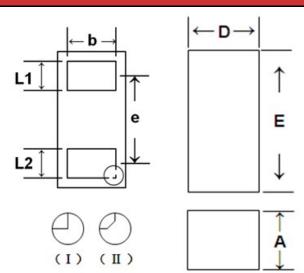








# 0402 PACKAGE OUTLINE DIMENSIONS



# **NOTE: ALL DIMENSIONS IN MM**

	MIN	NOM	MAX
D	0.55	0.60	0.65
E	0.95	1.00	1.05
L1	0.20	0.25	0.30
L2	0.20	0.25	0.30
Α	0.45	0.50	0.55
b	0.45	0.50	0.55
е		0.64BSC	

